MC SANGDEST MICROELECTRONICS

MBRF20100CT Green Products

Technical Data Data Sheet N0080, Rev. C

MBRF20100CT SCHOTTKY RECTIFIER

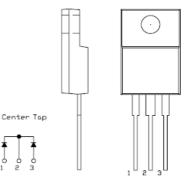
Applications:

- Switching power supply
- Converters
- Free-Wheeling diodes
- Reverse battery protection

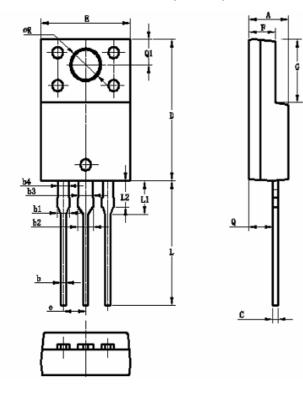
Features:

- 175 °C T_J operation
- Center tap configuration
- Low forward voltage drop
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability
- This is a Pb Free Device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request

Mechanical Dimensions (In mm)



OUTLINE DRAWING



Min 4.35 0.50 1.15 1.55 1.55 1.10 0.50 14.8 10.06	Max 4.65 0.75 1.402 1.802 1.65 1.35 0.75 15.2	Min 4.30 0.50 1.20 1.60 1.50 1.10 0.55 14.80	Max 4.70 0.75 1.45 1.85 1.75 1.35 0.75 15.20
0.50 1.15 1.55 1.55 1.10 0.50 14.8	0.75 1.402 1.802 1.65 1.35 0.75 15.2	0.50 1.20 1.60 1.50 1.10 0.55	0.75 1.45 1.85 1.75 1.35 0.75
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1.10 0.50 14.8	1.35 0.75 15.2	1.10 0.55	1.35 0.75
0.50 14.8	0.75 15.2	0.55	0.75
14.8	15.2		
-		14.80	15.20
10.06	40.00		
	10.26	9.96	10.36
2.46	2.62	2.55TYP	
2.85	3.15	2.80	3.20
6.50	6.90	6.50	6.90
12.70	13.70	12.70	13.70
3.40	3.80	3.40	4.00
2.60	3.00	-	-
2.60	2.80	2.50	2.90
		2.50	2.90
2.50	2.90	2.00	L
	2.60 2.60	2.60 3.00 2.60 2.80	2.60 3.00 - 2.60 2.80 2.50

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ITO-220AB



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Marking Diagram:



Where XXXXX is YYWWL

MBR	= Device Type
F	= Package type
20	= Forward Current (20A)
100	= Reverse Voltage (100V)
СТ	= Configuration
SSG	= SSG
YY	= Year
WW	= Week
L	= Lot Number

Cautions: Molding resin Epoxy resin UL:94V-0

Ordering Information:

Device	Package	Shipping
MBRF20100CT	ITO-220AB (Pb-Free)	50pcs / tube

For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification.

Maximum Ratings:

Characteristics	Symbol	Condition	Max.	Units
Peak Inverse Voltage	V _{RWM}	-	100	V
Max. Average Forward Current	I _{F(AV)}	50% duty cycle @T _C =133℃, rectangular wave form	10(Per leg) 20(Per device)	A
Max. Peak One Cycle Non- Repetitive Surge Current (per leg)	I _{FSM}	8.3 ms, half Sine pulse	150	А

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Electrical Characteristics:

Characteristics	Symbol	Condition	Max.	Units
Max. Forward Voltage Drop	V _{F1}	@ 5A, Pulse, T _J = 25 °C	0.80	V
(per leg)*		@ 10A, Pulse, T _J = 25 °C	0.90	
	V _{F2}	@ 5A, Pulse, T _J = 125 °C	0.70	V
		@ 10A, Pulse, T _J = 125 °C	0.80	
Max. Reverse Current at DC	I _{R1}	$@V_R = rated V_R$	1.0	mA
condition (per leg)		T _J = 25 °C		
Max. Reverse Current (per	I _{R2}	$@V_{R} = rated V_{R}$	6.0	mA
leg)*		T _J = 125 °C		
Repetitive peak reverse	Irrm	tp = 2 μs square F= 1 kHz	1	А
current				
Max. Junction Capacitance	CT	@V _R = 5V, T _C = 25 °C	250	pF
(per leg)		f _{SIG} = 1MHz		
Typical Series Inductance	Ls	Measured lead to lead 5 mm from	8.0	nH
(per leg)		package body		
Max. Voltage Rate of Change	dv/dt	-	10,000	V/µs
RSM Isolation Voltage	V _{ISO}	Clip mounting, the epoxy body	4500	V
(t = 1.0 second, R. H. < =30%,		away from the heatsink edge by		
T _A = 25 °C)		more than 0.110" along the lead		
		direction.		_
		Clip mounting, the epoxy body is	3500	
		inside the heatsink.		_
		Screw mounting, the epoxy body	1500	
		is inside the heatsink.		

* Pulse Width < 300µs, Duty Cycle <2%

Thermal-Mechanical Specifications:

Characteristics	Symbol	Condition	Specification	Units
Max. Junction Temperature	TJ	-	-55 to +175	°C
Max. Storage Temperature	T _{stg}	-	-55 to +175	°C
Maximum Thermal Resistance Junction to Case (per leg)	R _{θJC}	DC operation	3.5	°C/W
Approximate Weight	wt	-	2	g
Case Style		ITO-220AB		



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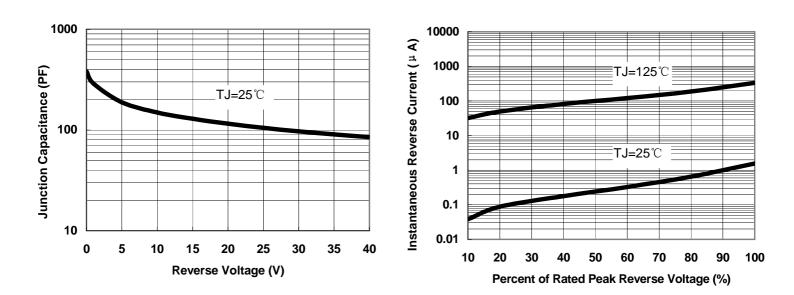


Fig.1-Typical Junction Capacitance

Fig.2-Typical Reverse Characteristics

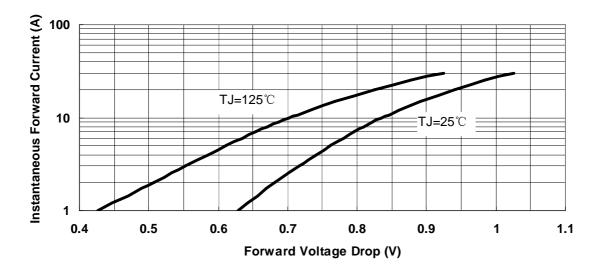


Fig.3-Typical Instantaneous Forward Voltage Characteristics

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